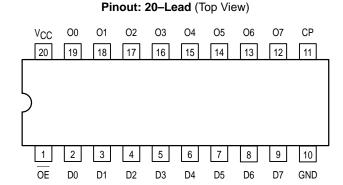
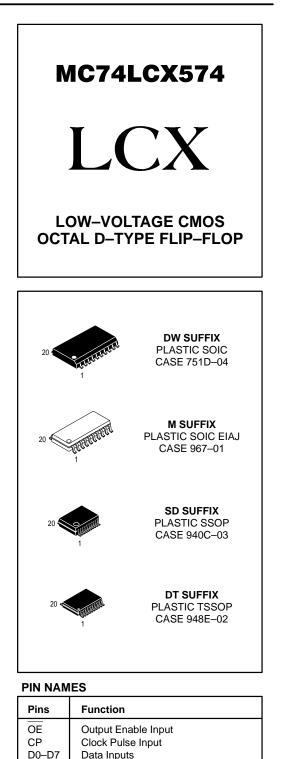
Low-Voltage CMOS Octal D-Type Flip-Flop Flow Through Pinout With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX574 is a high performance, non–inverting octal D–type flip–flop operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5V allows MC74LCX574 inputs to be safely driven from 5V devices.

The MC74LCX574 consists of 8 edge-triggered flip-flops with individual D-type inputs an<u>d 3</u>-state true outputs. The buffered clock and buffered Output Enable (OE) are common to all flip-flops. The eight flip-flops will store the state of individual D inputs that meet the setup and hold<u>time</u> requirements on the LOW-to-HIGH Clock (CP) transition. With the OE LOW, the <u>contents</u> of the eight flip-flops are available at the outputs. When the OE is HIGH, the outputs go to the high impedance state. The OE input level does not affect the operation of the flip-flops. The LCX574 flow through design facilitates easy PC board layout.

- Designed for 2.7 to 3.6V V_{CC} Operation
- 5V Tolerant Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When $V_{CC} = 0V$
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V



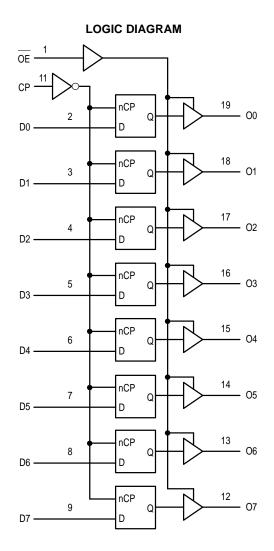




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3-State Outputs



	INPUTS		INTERNAL LATCHES	OUTPUTS	
OE	СР	Dn	Q	On	OPERATING MODE
L	$\uparrow \uparrow$	l h	L H	L H	Load and Read Register
L	\$	Х	NC	NC	Hold and Read Register
Н	1	Х	NC	Z	Hold and Disable Outputs
H	$\uparrow \uparrow$	l h	L	ZZ	Load Internal Register and Disable Outputs

H = High Voltage Level; h = High Voltage Level One Setup Time Prior to the Low-to-High Clock Transition; L = Low Voltage Level; I = Low Voltage Level One Setup Time Prior to the Low-to-High Clock Transition; NC = No Change; X = High or Low Voltage Level and Transitions are Acceptable; Z = High Impedance State; \uparrow = Low-to-High Transition; \uparrow = Not a Low-to-High Transition; For I_{CC} Reasons DO NOT FLOAT Inputs

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
VCC	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_I \le +7.0$		V
VO	DC Output Voltage	$-0.5 \le V_O \le +7.0$	Output in 3-State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
liк	DC Input Diode Current	-50	V _I < GND	mA
ЮК	DC Output Diode Current	-50	V _O < GND	mA
		+50	VO > VCC	mA
IO	DC Output Source/Sink Current	±50		mA
Icc	DC Supply Current Per Supply Pin	±100		mA
IGND	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied.
1. Output in HIGH or LOW State. IO absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
VO	Output Voltage (HIGH or LOW State) (3–State)	0 0		V _{CC} 5.5	V
Iон	HIGH Level Output Current, V _{CC} = 3.0V – 3.6V			-24	mA
IOL	LOW Level Output Current, $V_{CC} = 3.0V - 3.6V$			24	mA
ЮН	HIGH Level Output Current, V _{CC} = 2.7V – 3.0V			-12	mA
IOL	LOW Level Output Current, $V_{CC} = 2.7V - 3.0V$			12	mA
т _А	Operating Free–Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V _{IN} from 0.8V to 2.0V, V _{CC} = 3.0V	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = -40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	$2.7V \le V_{CC} \le 3.6V$	2.0		V
VIL	LOW Level Input Voltage (Note 2.)	$2.7V \le V_{CC} \le 3.6V$		0.8	V
VOH	HIGH Level Output Voltage	$2.7V \leq V_{CC} \leq 3.6V; \ I_{OH} = -100 \mu A$	V _{CC} - 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -12mA$	2.2		
		$V_{CC} = 3.0V; I_{OH} = -18mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -24mA$	2.2		
VOL	LOW Level Output Voltage	$2.7V \leq V_{CC} \leq 3.6V; \ I_{OL} = 100 \mu A$		0.2	V
		$V_{CC} = 2.7V; I_{OL} = 12mA$		0.4	
		V _{CC} = 3.0V; I _{OL} = 16mA		0.4	
		$V_{CC} = 3.0V; I_{OL} = 24mA$		0.55	

2. These values of V_I are used to test DC electrical characteristics only.

DC ELECTRICAL CHARACTERISTICS (continued)

			T _A = −40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
Ц	Input Leakage Current	$2.7V \leq V_{CC} \leq 3.6V; \ 0V \leq V_I \leq 5.5V$		±5.0	μΑ
loz	3-State Output Current	$\begin{array}{c} 2.7 \leq V_{CC} \leq 3.6 \text{V}; \ 0 \text{V} \leq \text{V}_{O} \leq 5.5 \text{V}; \\ \text{V}_{I} = \text{V}_{IH} \ \text{or} \ \text{V} \ \text{IL} \end{array}$		±5.0	μΑ
IOFF	Power–Off Leakage Current	$V_{CC} = 0V; V_I \text{ or } V_O = 5.5V$		10	μΑ
ICC	Quiescent Supply Current	$2.7 \leq V_{CC} \leq 3.6 \textrm{V}; ~\textrm{V}_{I} = \textrm{GND} ~\textrm{or} ~\textrm{V}_{CC}$		10	μΑ
		$2.7 \leq V_{CC} \leq 3.6 \textrm{V}; \ 3.6 \leq \textrm{V}_{I} \ \textrm{or} \ \textrm{V}_{O} \leq 5.5 \textrm{V}$		±10	μΑ
ΔICC	Increase in I _{CC} per Input	$2.7 \leq V_{CC} \leq 3.6 \text{V}; \text{ V}_{IH} = V_{CC} - 0.6 \text{V}$		500	μΑ

AC CHARACTERISTICS ($t_R = t_F = 2.5n_s$; $C_L = 50p_F$; $R_L = 500\Omega$)

				Lin	nits		
				T _A = -40°	C to +85°C		
			V _{CC} = 3.	0V to 3.6V	V _{CC} :	= 2.7V	
Symbol	Parameter	Waveform	Min	Мах	Min	Max	Unit
f _{max}	Clock Pulse Frequency	1	150				MHz
^t PLH ^t PHL	Propagation Delay CP to On	1	1.5 1.5	8.5 8.5	1.5 1.5	9.5 9.5	ns
^t PZH ^t PZL	Output Enable Time to HIGH and LOW Levels	2	1.5 1.5	8.5 8.5	1.5 1.5	9.5 9.5	ns
^t PHZ ^t PLZ	Output Disable Time from HIGH and LOW Levels	2	1.5 1.5	6.5 6.5	1.5 1.5	7.0 7.0	ns
t _S	Setup TIme, HIGH or LOW Dn to CP	1	2.5		2.5		ns
t _h	Hold Time, HIGH or LOW Dn to CP	1	1.5		1.5		ns
t _W	CP Pulse Width, HIGH or LOW	3	3.3		3.3		ns
^t OSHL ^t OSLH	Output-to-Output Skew (Note 3.)			1.0 1.0			ns

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
VOLP	Dynamic LOW Peak Voltage (Note 4.)	$V_{\mbox{\scriptsize CC}}$ = 3.3V, $C_{\mbox{\scriptsize L}}$ = 50pF, $V_{\mbox{\scriptsize IH}}$ = 3.3V, $V_{\mbox{\scriptsize IL}}$ = 0V		0.8		V
VOLV	Dynamic LOW Valley Voltage (Note 4.)	V_{CC} = 3.3V, C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V		0.8		V

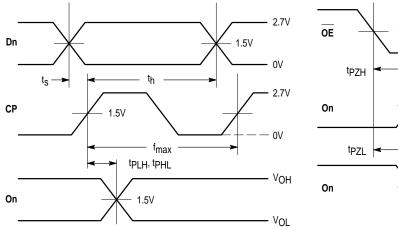
 Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = 3.3V, V_{I} = 0V or V_{CC}	7	pF
COUT	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10MHz, V_{CC} = 3.3V, V_{I} = 0V or V_{CC}	25	pF

MC74LCX574

2.7V

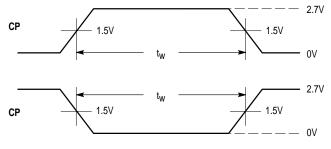




1.5V 1.5V 0V ^tPHZ V_{CC} V_{OH} – 0.3V 1.5V ≈ 0V ^tPLZ $\approx 3.0V$ 1.5V V_{OL} + 0.3V GND

 $t_R = t_F = 2.5ns$, 10% to 90%; f = 1MHz; $t_W = 500ns$

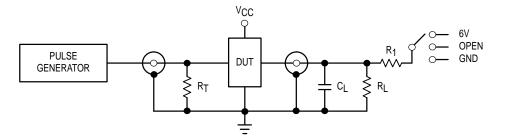
WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES



WAVEFORM 3 - PULSE WIDTH

 $t_R = t_F = 2.5$ ns (or fast as required) from 10% to 90%; Output requirements: $V_{OL} \le 0.8V$, $V_{OH} \ge 2.0V$



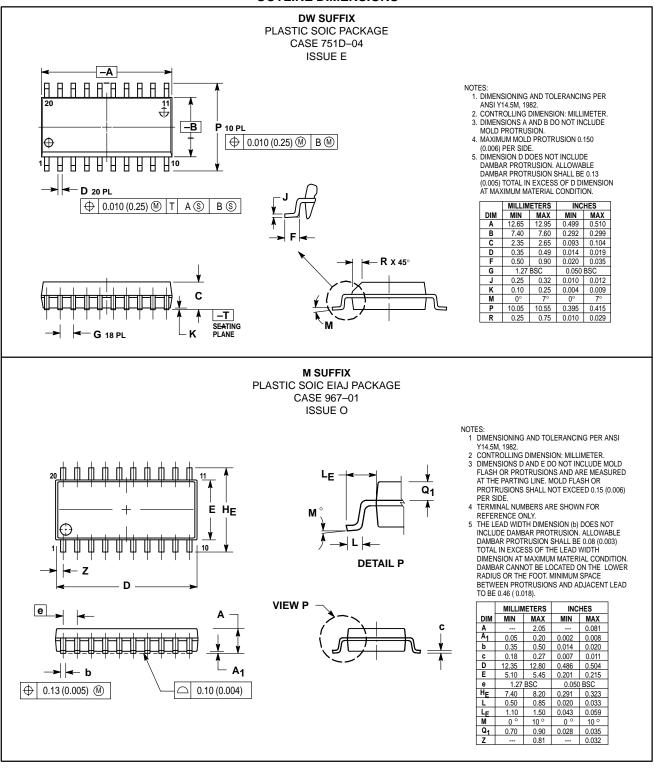


TEST	SWITCH
^t PLH ^{, t} PHL	Open
tPZL, tPLZ	6V
Open Collector/Drain t_{PLH} and t_{PHL}	6V
^t PZH ^{, t} PHZ	GND

 $\begin{array}{l} C_L = 50 pF \mbox{ or equivalent (Includes jig and probe capacitance)} \\ R_L = R_1 = 500 \Omega \mbox{ or equivalent} \\ R_T = Z_{OUT} \mbox{ of pulse generator (typically 50 \Omega)} \end{array}$

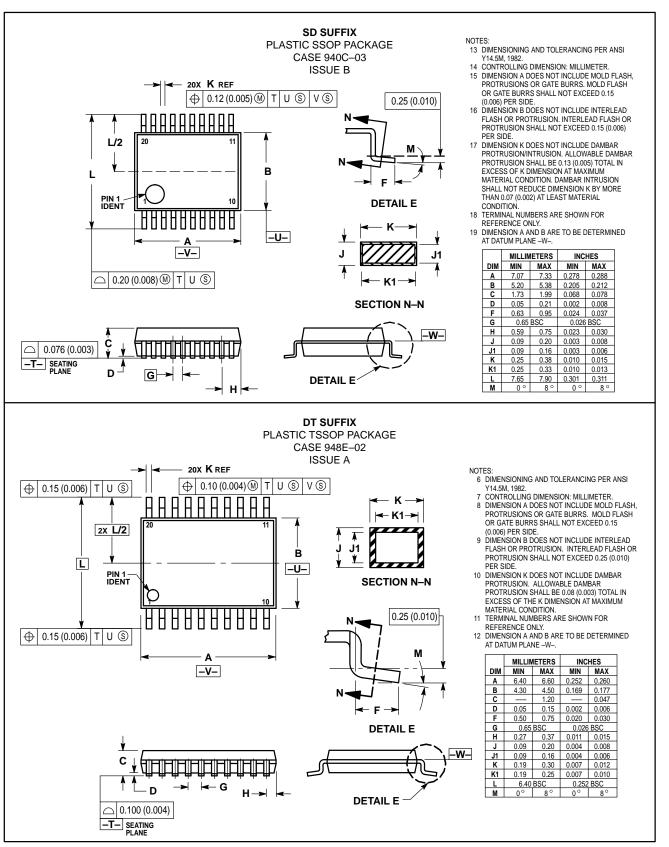
Figure 2. Test Circuit

OUTLINE DIMENSIONS



MC74LCX574

OUTLINE DIMENSIONS



MC74LCX574

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